The integration of magneto-electric and spintronic sensors to flexible electronics presents a huge potential for advancing flexible and wearable technologies. Magnetic nanowires are core components for building such devices. Therefore, realizing flexible magnetic nanowires with engineered magneto-elastic properties is key to flexible spintronic circuits, as well as creating unique pathways to explore complex flexible spintronic, magnonic, and magneto-plasmonic devices. Here, we demonstrate highly resilient flexible ferromagnetic nanowires on transparent flexible substrates for the first time. Through extensive magneto-optical Kerr experiments, exploring the Villari effect, we reveal an ultralow magnetostrictive constant in nanowires, a two-order reduced value compared to bulk values. In addition, the flexible magnetic nanowires exhibit remarkable resilience sustaining bending radii ∼5 mm, high endurance, and enhanced elastic limit compared to thin films of similar thickness and composition. The observed performance is corroborated by our micro-magnetic simulations and can be attributed to the reduced size and strong nanostructure-interface effects. Such stable magnetic nanowires with ultralow magnetostriction open up new opportunities for stable surface mountable and wearable spintronic sensors, advanced nanospintronic circuits, and for exploring novel strain-induced quantum effects in hybrid devices.

Introduction

Advancement in flexible electronics is the key to next-generation flexible sensors, wearable devices, and micro-nano medical applications. In the arena of such emerging developments, the integration of magnetic and spintronic components into flexible electronics presents a multitude of new prospects. Furthermore, flexible magnetic nanowires are prime ingredients for the recent realization of flexible spin circuits, as well as advancing magnetic sensors, spin-wave engineered magnonic, and novel flexible magneto-plasmonic components. Fundamentally, magnetic nanowires exhibit novel magnetic configurations induced by their geometry. Furthermore, unlike bulk magnetic systems with multidomain micromagnetic structure, nanowires approaching widths of 100–200 nm display an effective single domain behavior. In bulk systems, the competition between exchange and magnetostatic energy leads to the multidomain structure, whereas nanowires with diameters ∼100–200 nm approach critical size for single domain formation with shape induced anisotropy easy axis along the length of the wires. The magnetic configurations of nanowires are extensively utilized in lateral spin valves for their role as spin injectors and detectors, which have enormous application potential for flexible spin circuits.

Furthermore, while bulk systems are mainly dominated by the intrinsic magnetocrystalline anisotropy, at the nanoscale, the effects of shape, surface/interface, and stress anisotropy become increasingly relevant, opening the way to a wide variety of magnetic phenomena. This makes it fundamentally and technologically compelling to realize flexible magnetic nanowires ∼100–200 nm and determine their magnetoelastic limits. However, in contrast to widely studied magnetic thin films and applications, flexible magnetic nanowires and their response to bending stress have never been studied. This is primarily due to several challenges related to their fabrication, unknown adhesion and clamping effects to flexible substrates, and challenges in precisely capturing their magnetic response to strain. The phenomena of inverse magnetostriction, also known as the Villari effect, where altering the size of a magnetic material by applying stress results in modified magnetic characteristics, needs to be investigated here. The magnetostrictive behavior in bulk ferromagnetic metals such as Fe, Co, and Ni is well known and arises from spin-orbit
The effect can be simply pictured as an externally applied magnetic field, forcing the alignment of spins resulting in a distortion of electronic clouds, which induces a variation in interatomic distances. The link of exchange interaction with interatomic space or the magneto-elastic coupling makes magnetism quite sensitive to strain. Due to the finite size effects, nanowires exhibit unique scaling and phase transition behavior, making magnetostriction in ferromagnetic nanowires and their impacts non-trivial. Therefore, realizing and establishing the magneto-elastic limits of flexible magnetic nanowires will make a significant impact, fundamentally and technologically. In particular, engineering flexible magnetic nanowires with negligible magnetostriction could promote extraordinary resilience and hence stability upon bending in flexible devices, which could lead to translation of existing state-of-the-art and advanced spintronic technologies to flexible substrates.

In this work, we realize highly stable ferromagnetic nanowires on flexible polyethylene naphthalate (PEN), an emerging low roughness substrate (average RMS roughness $\sim 1.3$–$1.5$ nm) for flexible electronic applications. By optimizing the adhesion and fabrication conditions, we achieve a large-dense-array of non-interacting magnetic nanowires (shown in Fig. 1) with exceptional resilience upon bending. Through magneto-optic Kerr effect (MOKE) experiments, we comprehensively probe magnetism and Villari effect in ferromagnetic nanowires fabricated on flexible substrates subjected to bending radii up to $5$ mm to unlock magneto-elastic coupling. By performing micromagnetic simulations, we confirm and assess the magneto-elastic properties of the nanowires. These experiments and simulations reveal, for the first time, the remarkable resilient nature of the magnetic nanowires, with high yield strength and ultralow magnetostriction.

**Results and discussion**

For this work, we fabricated arrays of nanowires on flexible PEN substrates by nanofabrication techniques optimized for flexible substrates. In comparison to fabricating thin films, obtaining such nanowire arrays without metal residues is not straightforward. In particular, while photolithography and interference lithography processes are compatible with flexible substrates, these cannot reach down to single domain nanowires of width $200$ nm or below, magnetic nanowires that are of interest for flexible spin circuits. For this work, we employed optimized charge-mitigated e-beam lithography for flexible substrates, e-beam evaporation, and metal lift-off processing. The final nanowire array displayed in Fig. 1a consists of a layered structure of $3$ nm Ti$|$30 nm Co$|$4 nm Al stack, with good clear separation of nanowires over a large area $\sim 4$ mm $\times$ 4 mm. Nevertheless, utilizing these conditions, we obtained such large arrays for both $100$ nm and $200$ nm wide nanowires with up to $30$ nm of Co thickness. Considering the substrate roughness, we observed that an initial layer of $3$ nm Ti promotes uniform metal adhesion throughout the surface. In addition to these nanowire samples, we also prepared a flexible cobalt thin film as a reference having the same-layered structure. A key challenge of this study was to investigate the properties of nanowire samples mimicking real-world conditions of flexible devices. Magnetic nanowires exhibit sharp magnetization reversal process, i.e., the switching between the two antiparallel magnetic saturation states at a precise coercive field ($H_C$). Hence, the study of the magnetic properties of such a small nanostructure requires a high sensitivity, which needs to be optimized for measurements under a controlled amount of stress. To capture the magnetization reversal process for both nanowire and thin-film samples, we...
recorded magnetization versus field \( M(H) \) loops at room temperature, using a home-built longitudinal magneto-optic Kerr effect (L-MOKE) setup as depicted in Fig. 2a. To bend these samples stably, we fabricated special 3D printed curved sample holders with several radii of curvatures, providing stable support to the samples while allowing us to precisely control the curvature. The similar curvature at every point in the sample also ensures uniform stress throughout our samples. Shown in the lower panel of Fig. 2a, the 3D printed sample stage for sample mounting consisted of a curved mold with a square window cap to clamp the flexible substrate to the curve base (see Methods). The molds forcing the sample in a concave configuration induce a compressive stress, while the convex configuration applies a tensile stress on the sample.

For a specific radius of curvature of the sample holder \( R \), the induced strain \( \varepsilon \) on the sample is given by:

\[
\varepsilon = \frac{h + t}{2R} \frac{h + t}{\pi}
\]

where \( h \) is the thickness of the flexible PEN substrate, and \( t \) is the magnetic layer thickness. The corresponding stress \( \sigma \) exerted on the material, with Young modulus \( E \) and Poisson’s ratio \( \gamma \), can be calculated using eqn (2) given below:

\[
\sigma = \frac{\varepsilon E}{(1 - \gamma^2)}
\]

 Such stress induces a uniaxial magnetic anisotropy component with corresponding anisotropy energy \( E_\sigma \):

\[
E_\sigma = K_\sigma \sin^2 \theta = \frac{3}{2} \lambda_\sigma \sigma \sin^2 \theta
\]

where, \( K_\sigma \) is the stress-induced anisotropy constant, \( \lambda_\sigma \) the magnetostrictive constant of the material, and \( \theta \) is the angle between the magnetization and easy axis, with \( \lambda_\sigma = -60 \times 10^{-6} \) for bulk polycrystalline cobalt. The negative sign of \( \lambda_\sigma \) implies that the application of tensile stress promotes an anisotropy easy axis perpendicular to the applied stress, while compressive stress produces an easy axis parallel to it, as illustrated in Fig. 1b.

First, we probe the Co films by measuring \( M(H) \) curves after rotating the sample at different in-plane angles with respect to the applied field. Due to the polycrystalline nature of the sample, the random distribution of the easy axis of each grain should, in principle, average out the anisotropy, leading to a

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**Fig. 2** (a) Top panel: Scheme of magnetization measurements on nanowires (thin films) using longitudinal magneto-optic Kerr effect (L-MOKE) along with experimental arrangement consisting of laser and polarizer (P) for the emission of linearly polarized light, followed by the analyzer (A) and detector arrangement involving a lock-in amplifier (LiA) for measuring the reflected elliptically polarized light. Bottom panel (left to right): A 3D printed sample stage with a bent sample of a thin film and a cross-sectional view of the stable curved sample stub. (b) Representation of how compressive stress (corresponding to a concave geometry of the sample) and tensile stress (convex sample) induce hard and easy magnetic anisotropy axes respectively in ferromagnets with negative magnetostriction such as cobalt. (c) Saturation field as a function of the applied field angle. The fit to the data allows estimating a residual stress anisotropy of about 8.5(3) kJ m\(^{-3}\).
negligible effective value with no angular dependence.\textsuperscript{25} However, a weak but clear uniaxial anisotropy emerged, as revealed by the angular dependence of the saturation field extracted from $M(H)$ curves (see Fig. 2b), which indicates the high sensitivity of our setup to characterize magnetism in thin films faithfully. Note that the observed anisotropy is normal for magnetic thin films occurring due to intrinsic stress developed during the preparation process of thin films.\textsuperscript{26} By bending the substrate, we then applied different values of tensile and compressive stress perpendicular to the intrinsic easy axis, while measuring the $M(H)$ loops with the field applied parallel (Fig. 3a) and perpendicular to the film’s intrinsic easy axis (Fig. 3b). The results are consistent with the negative magnetostriction of cobalt, for which an external tensile (compressive) stress produces an additional anisotropy with easy axis perpendicular (parallel) to the stress direction. Consequently, such an additional stress-induced anisotropy can add to or compete against the intrinsic anisotropy resulting in an increase or decrease of the original coercivity, in accordance with the geometrical configuration, as illustrated in Fig. 3a and b. Here, combining eqn (1) and (2), we have estimated the external stress applied to the film as a function of the radius of curvature. For calculations, we have used Young’s modulus $E = 209$ GPa reported for nanocrystalline Co\textsuperscript{27} and a Poisson’s ratio $\gamma = 0.31$ of bulk Co,\textsuperscript{28} considering that both theoretical and experimental results on $\gamma$ show no appreciable deviation from the bulk value for nanostructured metallic alloys.\textsuperscript{29–31} This is supported by the fact that within the classical finite size effect regime, metal nanowires of the present dimensions exhibit characteristic Debye temperature\textsuperscript{17,19} of the same order as bulk values.

Using the saturation field $\mu_0H_{\text{sat}}$ along the hard axis induced by the applied tensile stress, we can estimate an effective anisotropy as:

$$K = \frac{\mu_0H_{\text{sat}}M_s}{2}$$ (4)

assuming the bulk saturation magnetization $M_s = 1.4$ MA m$^{-1}$.\textsuperscript{9} We verified this value for both the thin film and the nanowires by SQUID magnetometry. Despite being affected by considerable uncertainty, intrinsically due to the low moment and difficult estimation of Co’s precise and effective volume, we obtained $M_s$ values similar to the bulk value, in agreement with other recent experimental observations.\textsuperscript{32,33} In Fig. 3c, we present the experimental values of anisotropy as a function of in situ applied tensile stress. The stress was applied perpendicular to the intrinsic easy axis, as shown in the inset of Fig. 3a. A modified eqn (3), $K_{\text{eff}} = K_{\text{intr}} + \frac{3}{2}\lambda_\sigma\sigma$, that encompasses the intrinsic anisotropy of the film, was fitted to the $K_{\text{eff}}$ values within the elastic (linear) regime (Fig. 3c). The fit reveals a magnetostriction constant $\lambda_\sigma = -6.3(5) \times 10^{-6}$, which is one order of magnitude smaller than the value reported for bulk polycrystalline cobalt.\textsuperscript{34} Such a reduction is consistent with similar behavior observed previously in FeGa films.\textsuperscript{35} The fitting procedure was limited to the practical elastic regime of the sample, i.e., up to 2 GPa of external stress. Note that the film thickness is within the range for efficient stress transfer,\textsuperscript{16,37} and we did not notice any physical change or thin films to be detached from the substrates during or after the experiments. Beyond physical observations, the most sensitive way to detect permanent plastic deformation is offered by the magnetoelastic behavior itself, where we see a marked deviation from the expected linear elastic regime, only for 3 GPa of external stress. Therefore, in general, our method has the additional value of probing with high precision the mechanical properties of nanostructures, allowing the observation of the most extended elastic regime so far reported for Co thin films.

After confirming the mechanical stability and adhesion of our thin-film heterostructures on PEN, we focused on measuring the magnetic response of nanowires (NWs) fabricated with the same layered structure on PEN substrates. Cobalt nanowires with a width of 200 nm and a length of 2 μm are orga-

![Fig. 3](image-url) Room temperature $M(H)$ curves of Co film before bending (black curves), after a 2 GPa tensile stress (red curves), and a 2 GPa compressive stress (blue curves) applied perpendicularly to the intrinsic easy axis of the film. The curves are measured in the L-MOKE setup with the magnetic field parallel (a) and perpendicular (b) to the original easy axis, as depicted in insets. (c) Values of the effective anisotropy of the film under different tensile stress applied (calculated from eqn (4)). The red line shows the fit to the data within the elastic regime of the film.
nized in arrays (Fig. 1a), with a horizontal and vertical spacing pitch of 500 nm to minimize magnetic interactions between the individual nanowires. In contrast to continuous thin films, the shape anisotropy of the nanowires establishes a strong anisotropy easy axis along its length. Applying the magnetic field parallel to the length of the nanowires, we recorded $M(H)$ loops under different values of applied stress. The configuration of the applied stress, magnetic field, and nanowire geometry, along with the scheme of measurements on nanowires, are displayed in Fig. 1b. For the nanowires, tensile and compressive stress is applied perpendicularly to the shape anisotropy easy axis. A comparison of the $M(H)$ loops under initial flat conditions, as well as the loops measured with an applied tensile and compressive stress of ~2 GPa, is displayed in Fig. 4a. A summary of the extracted coercivities for different applied stress is presented in Fig. 4b. The observed trend of coercivity enhancement with tensile stress and overall reduction with compressive stress is in tune with the fact that tensile stress strengthens the anisotropy along the intrinsic easy axis, increasing the coercivity and the compressive stress acts oppositely. With the large shape anisotropy of the nanowires, the magnetization reversal can be reasonably described by the Wolfarth–Stoner model. Therefore, for an $M(H)$ loop measured along the easy axis of an individual single nanowire, we can attribute its behavior to that of a single magnetic domain structure, where $H_C \sim H_{sat}$, hence we can rearrange eqn (3) and (4):

$$H_C = H_C^c + \frac{3}{M_S} \lambda_s \sigma$$

where $H_C^c$ is the original intrinsic coercivity. Using $M_S = 1.4$ MA m$^{-1}$, valid also in cobalt nanowires, we fit $H_C$ versus stress using eqn (5) to estimate the magnetostriction in the case of tensile stress yielding the anisotropy easy axis along the long axis of the nanowire. Strikingly, tensile stress reveals an ultra-small $\lambda_s = -9(2) \times 10^{-7}$, which is nearly two orders of magnitude smaller than bulk Co value. Therefore, the magnetic behavior of nanowires remains mostly unaltered despite the application of stress.

Although simple, this model allows describing a clear picture of the magneto-elastic properties of our nanowires from the evolution of coercivity, a key parameter for the application of magnetic nanowires in the context of flexible-devices. The present nanowires are above the conventional size for a coherent reversal of the magnetization, hence one cannot exclude a priori eventual domain wall formation and motion and its role on the observed coercivity. Furthermore, while the external stress induces a corresponding stress anisotropy over the entire NW, locally, they are constituted by Co nanograins with intrinsic magneto crystalline anisotropy and randomly oriented easy axis. This randomization averages out the overall effective magneto crystalline anisotropy; nevertheless, it is essential to identify its eventual influence over the magnetization reversal. Finally, one could argue that the presence of a dominating shape anisotropy hinders any other effect of external stress. The complexity of the overall scenario has never been systematically investigated, and therefore, to find answers to these questions, we have created a micromagnetic model of the nanowires using MuMax$^3$, a GPU accelerated micromagnetic simulation software (details in methods).

As shown in Fig. 5a, we could obtain both qualitative and quantitative description of the experimental data by using typical values of saturation magnetization ($M_S = 1.4$ MA m$^{-1}$) and adjusting the exchange stiffness to take into account an effective room temperature exchange across the nanocrystalline structure ($A_{ex} = 17.5$ pJ m$^{-1}$). In addition, we have

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**Fig. 4** (a) Room-temperature $M(H)$ loops measured along the length (easy axis) of the Co nanowires in flat and applied stress conditions. (b) Coercivity for the NWs extracted from $M(H)$ loops as a function of in situ applied stress along with linear fits to eqn (5).
tested the role of the magnetocrystalline anisotropy repeating the simulation with and without a random anisotropy model (RAM), including a grainy structure (10 nm grains) with typical intrinsic magnetocrystalline anisotropy ($K = 520$ kJ m$^{-3}$) and random distribution of easy axis. In both cases (with and without the use of RAM), we get the same results for both stressed and unstressed systems. This confirms that the intrinsic magnetocrystalline anisotropy has a negligible influence due to the random direction of the easy axis among grains and the dominant effect of the shape anisotropy. The second important observation is that the NWs magnetization never forms domain walls, but just minimal curling at the edges at fields close to the magnetization reversal, which happens in a coherent-like mode, under the driving force of the shape anisotropy, as evident by the insets of Fig. 5a. This reinforces the significance of our basic model used to treat the experimental data. To test the effect of external stress we have implemented its effective uniaxial anisotropy in the model. First, the magnitude of the stress anisotropy has been calculated according to eqn (3) using the values of external applied stress and the effective magnetostriction constant $\lambda_{\text{eff}}$ obtained from the Co thin film samples. The coercivity of the NWs varies according to the trend presented in Fig. 5b and c. It is evident that if the nanowires would have the same magnetostriction as the thin film, their variation of coercivity would not be quenched by intrinsic magnetocrystalline anisotropy or by the shape anisotropy and the increment of $H_C$ would be much larger than what was experimentally observed. Repeating the same simulations using the experimental effective magnetostriction constant $\lambda_{\text{NWs}}$ of the NWs, we could reproduce the experimental $H_C$ vs. stress trend (Fig. 5b and c). Hence, these results strongly reinforce the existence of an ultra-small effective magnetostriction constant in the NWs, much smaller than that of the thin film.

The implementation of magnetic nanowires in real-world flexible device applications demands robust mechanical stability. To test the resilience of our nanowires on the flexible substrates, we performed bending of the wires 100 times with a radius of curvature of $\sim 3$ GPa. As evident in Fig. 6a, the hysteresis behavior of the nanowires is faithfully restored, even after 100 bending cycles. We observed similar robust behavior...
in nanowires with lower width (see Fig. S1†). To check for deviations accrued during bending, we set the samples back to the flat configuration after each cycle of bending stress and performed measurements in the flat configuration. The result of such bending tests for nanowires as compared to the Co thin films of similar thickness is displayed in Fig. 6b. As evident here, for thin films, stress applied in different directions up to a value of 2 GPa did not induce any permanent deformation, while stress ~3 GPa permanently increases the original coercivity (nearly 40% increase), which is a signature of the plastic deformation of the sample. This is because, after the plastic deformation, when the substrate is brought back to its original flat configuration, the elongated sample retains tensile stress, which leads to the observed higher coercivity. From these results, we can conclude that the yield strength, the maximum stress that a film can sustain before permanent plastic deformation, surpasses 2 GPa, which is a significantly higher value compared to bulk Co and it is in tune with studies performed on thicker nanocrystalline films. The normalized $H_c$ versus subjected stress plot reveals that nanowires can sustain higher stress than thin films of the same thickness on PEN, which indicates an enhanced elastic limit of at least 3 GPa in the case of nanowires. These experiments enable us to conclusively demonstrate that the cobalt nanowires are highly resilient and endure an extreme bending radius ~5 mm (~1.4% strain) of the flexible substrate, which is of fundamental significance to develop stable flexible spintronic and magneto-electric sensors.

The high resilience of the cobalt nanowire demonstrated here is non-trivial but feasible considering the fact that improved elastic properties can be anticipated for nanostructured metals. Artificially structured magnets display unusual magnetic properties, due to the unique atomic environment at the surface/interface, characterized by missing bonds or bonding between different species. The high concentration of topological defects at the grain boundaries and surface can lead to a magnetostrictive behavior contrasting bulk magnetostriction. Specifically, localized magnetostrictive strains at the interfaces are responsible for surface magnetostriction contributions. For magnetic thin films, the surface magnetostriction competes with the bulk value, leading to the linear dependence of the effective magnetostriction constant on the inverse thickness in accordance with Szymczak's empirical model. The model has been successfully employed to characterize the behavior of thin films for Fe and Co-based alloys. A generalization to the Szymczak model for nanowires can be made as $\lambda_{\text{eff}} = \lambda_{\text{bulk}} + \lambda_{\text{surface}}$ (S/V), where an enhanced surface to volume ratio (S/V) could bring down the effective magnetostriction $\lambda_{\text{eff}}$ as observed in our experiments. Additional contributions to the deviation with respect to bulk can emerge from the eventual strain at the substrate interface, the surface roughness of the system, and possible crystalline structural reorganization in the thin layer. This implies that the further reduction of the effective magnetostriction to the reduced dimensionality of the NWs from 2D to 1D geometry is due to enhanced S/V and the enhanced local topological modifications and nanostructured interfaces, making the surface magnetostriction properties dominant over the bulk behavior. For each step of reduced dimensionality (bulk $\rightarrow$ film $\rightarrow$ NWs), nearly one order reduction in the magnitude of $\lambda_{\text{eff}}$ has been observed. Hence, our experiments demonstrate, for the first time, that ultralow effective magnetostriction resulting in the coercivity of nanowires remains nearly unaltered up to large bending radii of curvature (~5 mm). The high elastic limit (at least 3 GPa), ultralow magnetostriction, and the stability of the magnetic properties after 100 cycles of bending suggest a highly resilient magneto-elastic coupling in nanowires fabricated on flexible PEN.

For a broad spectrum of applications, the quenched magnetostriction forms the basis for developing stable magnetic
sensors, spintronics, and novel magneto-plasmonic applications that can be integrated to advance flexible electronics and wearable sensing technologies. Flexible magnetic nanowires with high magneto-elastic resilience with no mechanical fatigue is of principal advantage to devices, where one does not desire any change in magnetic properties and device performance due to the bending of magnetic elements but aims for extreme stability, for instance, in surface mounted sensors, steady magnetic switches, and spin valves. Over the past decade, the field of spintronics has seen rapid progress in the direction of planar multi-terminal spin circuits, made possible due to the advent of graphene and other graphene-like two dimensional (2D) crystals. In metal or graphene planar spin devices, ferromagnetic nanowires are widely employed to generate and detect spin current. The recent flexible spin circuits of graphene opened a new door to utilize the exceptional resilience of 2D materials for flexible 2D spintronics. Here, the current work provides crucial advancement in achieving magnetically and mechanically stable ferromagnetic nanowires as electrodes, which is vital for harnessing strain-induced band structure quantum changes in 2D materials spin valves for novel sensing and transduction. The resilience of ferromagnets can also enable unveiling the impact of strain on novel spin interfaces for strain-induced tuning of spin polarization can also enable unveiling the impact of strain on novel spin interfaces for strain-induced tuning of spin polarization. For instance, in the reduction in size and dimensionality. The magnetic properties and resilience opens up new avenues for probing and exploiting strain-induced effects on interfaces and novel spacers in planar spintronic applications while being useful for creating advanced applications in flexible spintronics, magnonics, and magneto-plasmonics.

Materials and methods

Sample preparation

Cobalt thin film and nanowire samples were prepared on flexible polyethylene naphthalate substrate obtained from DuPont. Nanowire samples were prepared by bilayer resist e-beam lithography that provides an undercut for ease in liftoff. First, e-beam lithography was performed to make patterned stripes of nanowires with an aspect ratio of 10. Subsequently, a metallic film consisting of a layer of 3 nm of titanium, 30 nm of cobalt, and finally, a layer of 4 nm of aluminum to protect the cobalt layer from oxidation was deposited by electron beam metal evaporation technique. Finally, liftoff in hot acetone was performed to obtain the arrays of nanowires on a substrate ~1 cm x 1 cm.

Magnetic characterization

Magnetic characterization was carried out at room temperature using a home-built longitudinal magneto-optical Kerr effect (L-MOKE) setup. The MOKE setup was equipped with a red laser (wavelength 660 nm) modulated by a wave generator at 13 kHz and a lock-in amplifier SR 830 that allows collecting the signal from a Si photodetector with an amplitude of few tens of nA. To perform the stress-dependent magnetization measurements, we fabricated 3D printed sample holders having several radii of curvatures. The samples were placed on the curved base, and an upper frame-holder with an internal square window that kept them in place. The frame ensures a uniform radius of curvature for the sample and allows the laser to hit the central area of the sample. To induce a controlled amount of stress, the samples were inserted into different sample holders, each with a specific curvature. To increase the signal-to-noise ratio, several hundred curves were measured and averaged to obtain the final $M(H)$ curves. Besides, for each bending curvature, at least 10 hysteresis loops were measured for the same applied stress focusing the laser spot on different regions of the pattern, and the values of the parameters, such as the coercivity, were averaged to consider any possible minor variations of effective local stress applied in different positions of the samples. All data are reported with the corresponding standard deviation. To validate our experimental findings, the experiments have been repeated on 3 different thin films and nanowires arrays obtaining equivalent results.

Micromagnetic simulations

Micromagnetic simulations were performed with MuMax³, a GPU accelerated simulation software. Commonly reported values of saturation magnetization $M_S = 1.4$ MA m⁻¹ and
exchange stiffness constant $A_{ex} = 17.5 \text{ pJ m}^{-1}$ of Co$^{59}$ were used to obtain results consistent with the experimental data. Periodic boundary conditions were applied repeating the simulation volume 10 times in $X$ and $Y$ directions to avoid limited size effects.$^{60}$ To accurately reproduce the sample, the system was discretized in cubic cells of $\sim 2.7 \text{ nm}$ edge, being smaller than the Co exchange length $l_{ex} = (2A/\mu_0M_S^2)^{1/2} = 3.4 \text{ nm}$. To implement a random anisotropy model, the sample was divided into grains with an average grain size of 10 nm using a Voronoi tessellation. The micromagnetic code includes the calculation of the demagnetization field produced by the specific geometry of the simulated nanowires and its effects on the total energy of the system.

## Conflicts of interest

The authors declare no competing interests.

## Acknowledgements

The authors acknowledge the VR starting grant (no. 2016-03278) from the Swedish Research Council, funding from the Olle Engkvist Foundation, and the Carl-Tryggers Foundation. The authors thank Olof Karis, Tapati Sarkar, and Jean-Francois Dayen for helpful feedback and H. Mishra and A. Patel for assistance.

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